

# 4-Kb and 8-Kb I<sup>2</sup>C CMOS Serial EEPROM



#### **FEATURES**

- Standard and Fast I<sup>2</sup>C Protocol Compatible
- Supports 1MHz Clock Frequency
- 1.7 V to 5.5 V Supply Voltage Range
- 16-Byte Page Write Buffer
- Hardware Write Protection for entire memory
- Schmitt Triggers and Noise Suppression Filters on I<sup>2</sup>C Bus Inputs (SCL and SDA)
- Low power CMOS technology
- 1,000,000 program/erase cycles
- 100 year data retention
- Industrial temperature range
- RoHS-compliant TSOT-23 5-lead and SOIC 8-lead packages

#### DESCRIPTION

The CAT24AA04/24AA08 are 4-Kb and 8-Kb CMOS Serial EEPROM devices internally organized as 512x8/1024x8 bits.

They feature a 16-byte page write buffer and support 100kHz, 400kHz and 1MHz I<sup>2</sup>C protocols.

In contrast to the CAT24C04/24C08, the CAT24AA04/24AA08 have no external address pins, and are therefore suitable in applications that require a single CAT24AA04/08 on the f<sup>2</sup>C bus.

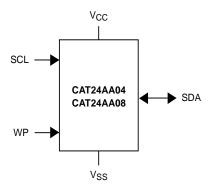
For Ordering Information details, see page 12.

#### PIN CONFIGURATION

SOIC (W)			-	SOT	-23 (TI	٠,	
NC	1	8	$V_{CC}$		301	-23 (11	ı
NC	2	7	WP	SCL	1	5	WP
NC	3	6	SCL	$V_{SS}$	2		
IVC	3	U	JOL	SDA	3	1	$V_{CC}$
$V_{\mathtt{SS}}$	4	5	SDA	SDA	٥	7	v CC

For the location of Pin 1, please consult the corresponding package drawing.

#### **FUNCTIONAL SYMBOL**





#### **PIN FUNCTIONS**

Pin Name	Function
SDA	Serial Data Input/Output
SCL	Clock Input
WP	Write Protect
V <sub>CC</sub>	Power Supply
$V_{SS}$	Ground
NC	No Connect

## **CAT24AA04, CAT24AA08**

## **ABSOLUTE MAXIMUM RATINGS** (1)

Parameters	Ratings	Units
Storage Temperature	-65 to +150	٥C
Voltage on any Pin with Respect to Ground <sup>(2)</sup>	-0.5 to +6.5	V

## REABILITY CHARACTERISTICS(3)

Symbol	Parameter	Min	Units
N <sub>END</sub> <sup>(4)</sup>	Endurance	1,000,000	Program/Erase Cycles
$T_DR$	Data Retention	100	Years

#### D.C. OPERATING CHARACTERISTICS

 $V_{CC}$  = 1.7 V to 5.5 V,  $T_A$  = -40°C to 85°C, unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Max	Units
I <sub>CCR</sub>	Read Current	Read, f <sub>SCL</sub> = 400 kHz		0.5	mA
I <sub>ccw</sub>	Write Current	Write, f <sub>SCL</sub> = 400 kHz		1	mΑ
I <sub>SB</sub>	Standby Current	All I/O Pins at GND or V <sub>CC</sub>		1	μΑ
ΙL	I/O Pin Leakage	Pin at GND or V <sub>CC</sub>		1	μΑ
V <sub>IL</sub>	Input Low Voltage		-0.5	V <sub>CC</sub> x 0.3	V
V <sub>IH</sub>	Input High Voltage		V <sub>CC</sub> x 0.7	V <sub>CC</sub> + 0.5	V
V <sub>OL1</sub>	Output Low Voltage	$V_{CC} \ge 2.5 \text{ V}, I_{OL} = 3.0 \text{ mA}$		0.4	V
V <sub>OL2</sub>	Output Low Voltage	$V_{CC}$ < 2.5 V, $I_{OL}$ = 1.0 mA		0.2	V

## PIN IMPEDANCE CHARACTERISTICS

 $V_{CC}$  = 1.7 V to 5.5 V,  $T_A$  = -40°C to 85°C, unless otherwise specified.

Symbol	Parameter	Conditions	Max	Units
C <sub>IN</sub> (3)	SDA I/O Pin Capacitance	$V_{IN} = 0V$	8	pF
C <sub>IN</sub> <sup>(3)</sup>	Input Capacitance (other pins)	$V_{IN} = 0V$	6	pF
I <sub>WP</sub> <sup>(5)</sup>	WP Input Current	$V_{IN} < 0.5 \text{xV}_{CC}, V_{CC} = 5.5 \text{ V}$	200	
		$V_{IN} < 0.5 \text{xV}_{CC}, \ V_{CC} = 3.3 \ \text{V}$	150	^
		$V_{IN} < 0.5 \text{xV}_{CC}, V_{CC} = 1.8 \text{ V}$	100	μA
		$V_{IN} > 0.5 x V_{CC}$	1	

- (1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.
- (2) The DC input voltage on any pin should not be lower than -0.5V or higher than  $V_{CC}$  + 0.5V. During transitions, the voltage on any pin may undershoot to no less than -1.5V or overshoot to no more than  $V_{CC}$  + 1.5V, for periods of less than 20ns.
- (3) These parameters are tested initially and after a design or process change that affects the parameter according to appropriate AEC-Q100 and JEDEC test methods.
- (4) Page Mode @ 25°C
- (5) When not driven, the WP pin is pulled down to GND internally. For improved noise immunity, the internal pull-down is relatively strong; therefore the external driver must be able to supply the pull-down current when attempting to drive the input HIGH. To conserve power, as the input level exceeds the trip point of the CMOS input buffer (~ 0.5 x V<sub>CC</sub>), the strong pull-down reverts to a weak current source.

## A.C. CHARACTERISTICS (1)

 $V_{CC}$  = 1.7 V to 5.5 V,  $T_A$  = -40°C to 85°C, unless otherwise specified.

		Standard V <sub>CC</sub> = 1.7V - 5.5V		Fast V <sub>CC</sub> = 1.7V - 5.5V		1 MHz V <sub>CC</sub> = 2.5V - 5.5V		Units
Symbol	Parameter	Min	Max	Min	Max	Min	Max	
F <sub>SCL</sub>	Clock Frequency		100		400		1000	kHz
t <sub>HD:STA</sub>	START Condition Hold Time	4		0.6		0.25		μs
$t_{LOW}$	Low Period of SCL Clock	4.7		1.3		0.5		μs
t <sub>HIGH</sub>	High Period of SCL Clock	4		0.6		0.5		μs
t <sub>SU:STA</sub>	START Condition Setup Time	4.7		0.6		0.25		μs
t <sub>HD:DAT</sub>	Data In Hold Time	0		0		0		ns
t <sub>SU:DAT</sub>	Data In Setup Time	250		100		100		ns
$t_R^{(2)}$	SDA and SCL Rise Time		1000		300		300	ns
t <sub>F</sub> <sup>(2)</sup>	SDA and SCL Fall Time		300		300		100	ns
t <sub>su:sto</sub>	STOP Condition Setup Time	4		0.6		0.25		μs
t <sub>BUF</sub>	Bus Free Time Between STOP and START	4.7		1.3		0.5		μs
t <sub>AA</sub>	SCL Low to Data Out Valid		3.5		0.9		0.4	μs
t <sub>DH</sub>	Data Out Hold Time	100		50		50		ns
T <sub>i</sub> <sup>(2)</sup>	Noise Pulse Filtered at SCL and SDA Inputs		100		100		100	ns
t <sub>SU:WP</sub>	WP Setup Time	0		0		0		μs
t <sub>HD:WP</sub>	WP Hold Time	2.5		2.5		1		μs
t <sub>WR</sub>	Write Cycle Time		5		5		5	ms
t <sub>PU</sub> <sup>(2, 3)</sup>	Power-up to Ready Mode		1		1		1	ms

#### **A.C. TEST CONDITIONS**

Input Levels	0.2 x V <sub>CC</sub> to 0.8 x V <sub>CC</sub>
Input Rise and Fall Times	≤ 50ns
Input Reference Levels	0.3 x V <sub>CC</sub> , 0.7 x V <sub>CC</sub>
Output Reference Levels	0.5 x V <sub>CC</sub>
Output Load	Current Source: $I_{OL} = 3mA (V_{CC} \ge 2.5V); I_{OL} = 1mA (V_{CC} < 2.5V); C_L = 100pF$

- (1) Test conditions according to "A.C. Test Conditions" table.
- (2) Tested initially and after a design or process change that affects this parameter.
- (3)  $t_{\text{PU}}$  is the delay between the time  $V_{\text{CC}}$  is stable and the device is ready to accept commands.

## **POWER-ON RESET (POR)**

Each CAT24AA04/08 incorporates Power-On Reset (POR) circuitry which protects the internal logic against powering up in the wrong state. The device will power up into Standby mode after  $V_{\rm CC}$  exceeds the POR trigger level and will power down into Reset mode when  $V_{\rm CC}$  drops below the POR trigger level.

This bi-directional POR behavior protects the device against brown-out failure, following a temporary loss of power.

#### PIN DESCRIPTION

**SCL:** The Serial Clock input pin accepts the clock signal generated by the Master.

**SDA:** The Serial Data I/O pin accepts input data and delivers output data. In transmit mode, this pin is open drain. Data is acquired on the positive edge, and delivered on the negative edge of SCL.

**WP:** When the Write Protect input pin is forced HIGH by an external source, all write operations are inhibited. When the pin is not driven by an external source, it is pulled LOW internally.

#### **FUNCTIONAL DESCRIPTION**

The CAT24AA04/08 supports the Inter-Integrated Circuit (I<sup>2</sup>C) Bus protocol. The protocol relies on the use of a Master device, which provides the clock and directs bus traffic, and Slave devices which execute requests. The CAT24AA04/08 operates as a Slave device. Both Master and Slave can transmit or receive, but only the Master can assign those roles.

## I<sup>2</sup>C BUS PROTOCOL

The 2-wire  $I^2C$  bus consists of two lines, SCL and SDA, connected to the  $V_{CC}$  supply via pull-up resistors. The Master provides the clock to the SCL line, and the Master and Slaves drive the SDA line. A '0' is transmitted by pulling a line LOW and a '1' by releasing it HIGH. Data transfer may be initiated only when the bus is not busy (see A.C. Characteristics). During data transfer, SDA must remain stable while SCL is HIGH.

#### START/STOP CONDITION

An SDA transition while SCL is HIGH creates a START or STOP condition (Figure 1). A START is generated by a HIGH to LOW transition, while a STOP is generated by a LOW to HIGH transition. The START acts like a wake-up call. Absent a START, no Slave will respond to the Master. The STOP completes all commands.

#### **Device Addressing**

The Master addresses a Slave by creating a START condition and then broadcasting an 8-bit Slave address (Figure 2). The four most significant bits of the Slave address are 1010 (Ah). The next three bits from the Slave address byte are assigned as shown in Figure 2, where  $a_9$  and  $a_8$  are internal address bits. The last bit, R/W, instructs the Slave to either provide (1) or accept (0) data, i.e. it specifies a Read (1) or a Write (0) operation.

#### Acknowledge

During the 9<sup>th</sup> clock cycle following every byte sent onto the bus, the transmitter releases the SDA line, allowing the receiver to respond. The receiver then either acknowledges (ACK) by pulling SDA LOW, or does not acknowledge (NoACK) by letting SDA stay HIGH (Figure 3). Bus timing is illustrated in Figure 4.

Figure 1: Start/Stop Timing

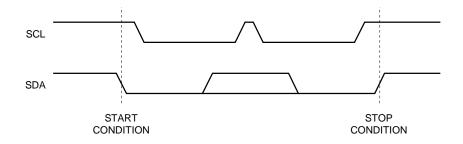


Figure 2: Slave Address Bits

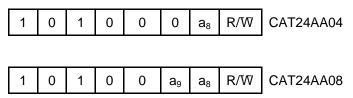


Figure 3: Acknowledge Timing

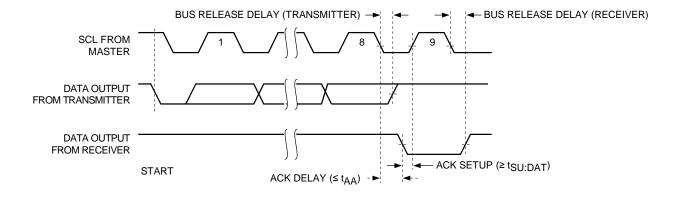
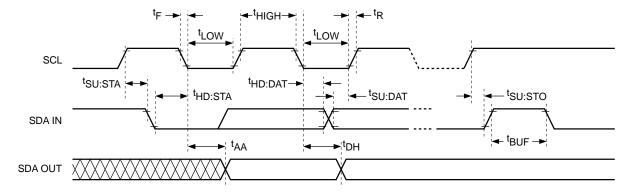


Figure 4: Bus Timing



#### WRITE OPERATIONS

#### **Byte Write**

To write data to memory, the Master creates a START condition on the bus and then broadcasts a Slave address with the R/W bit set to '0'. The Master then sends an address byte and a data byte and concludes the session by creating a STOP condition on the bus. The Slave responds with ACK after every byte sent by the Master (Figure 5). The STOP starts the internal Write cycle, and while this operation is in progress ( $t_{WR}$ ), the SDA output is tri-stated and the Slave does not acknowledge the Master (Figure 6).

#### **Page Write**

The Byte Write operation can be expanded to Page Write, by sending more than one data byte to the Slave before issuing the STOP condition (Figure 7). Up to 16 distinct data bytes can be loaded into the internal Page Write Buffer starting at the address provided by the Master. The page address is latched, and as long as the Master keeps sending data, the internal byte address is incremented up to the end of page, where it then wraps around (within the page). New data can therefore replace data loaded earlier. Following the STOP, data loaded during the Page Write session will be written to memory in a single internal Write cycle ( $t_{WR}$ ).

#### **Acknowledge Polling**

The acknowledge (ACK) polling routine can be used to take advantage of the typical write cycle time. Once the stop condition is issued to indicate the end of the host's write operation, the CAT24AA04/08 initiates the internal write cycle. The ACK polling can be initiated immediately. This involves issuing the start condition followed by the slave address for a write operation. If the CAT24AA04/08 is still busy with the write operation, NoACK will be returned. If the CAT24AA04/08 device has completed the internal write operation, an ACK will be returned and the host can then proceed with the next read or write operation.

#### **Hardware Write Protection**

With the WP pin held HIGH, the entire memory is protected against Write operations. If the WP pin is left floating or is grounded, it has no impact on the Write operation. The state of the WP pin is strobed on the last falling edge of SCL immediately preceding the 1<sup>st</sup> data byte (Figure 8). If the WP pin is HIGH during the strobe interval, the Slave will not acknowledge the data byte and the Write request will be rejected.

### **Delivery State**

The CAT24AA04/08 is shipped erased, i.e., all bytes are FFh.

Figure 5: Byte Write Sequence

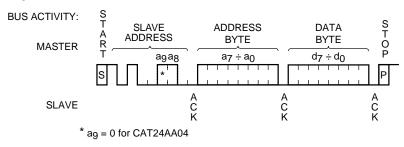


Figure 6: Write Cycle Timing

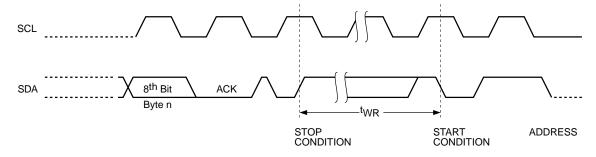


Figure 7: Page Write Sequence

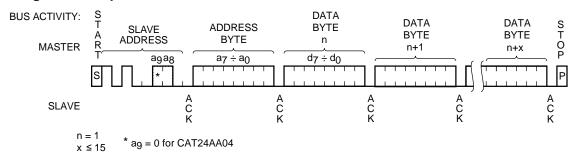
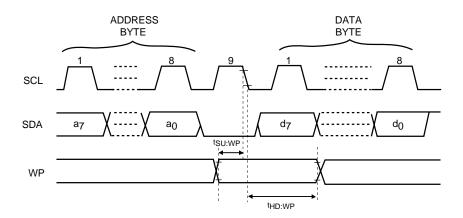


Figure 8: WP Timing



## **READ OPERATIONS**

#### **Immediate Read**

To read data from memory, the Master creates a START condition on the bus and then broadcasts a Slave address with the R/W bit set to '1'. The Slave responds with ACK and starts shifting out data residing at the current address. After receiving the data, the Master responds with NoACK and terminates the session by creating a STOP condition on the bus (Figure 9). The Slave then returns to Standby mode.

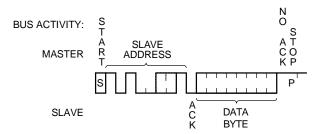
#### **Selective Read**

To read data residing at a specific address, the selected address must first be loaded into the internal address register. This is done by starting a Byte Write sequence, whereby the Master creates a START condition, then broadcasts a Slave address with the R/W bit set to '0' and then sends an address byte to the Slave. Rather than completing the Byte Write sequence by sending data, the Master then creates a START condition and broadcasts a Slave address with the R/W bit set to '1'. The Slave responds with ACK after every byte sent by the Master and then sends out data residing at the selected address. After receiving the data, the Master responds with NoACK and then terminates the session by creating a STOP condition on the bus (Figure 10).

#### **Sequential Read**

If, after receiving data sent by the Slave, the Master responds with ACK, then the Slave will continue transmitting until the Master responds with NoACK followed by STOP (Figure 11). During Sequential Read the internal byte address is automatically incremented up to the end of memory, where it then wraps around to the beginning of memory.

Figure 9: Immediate Read Sequence and Timing



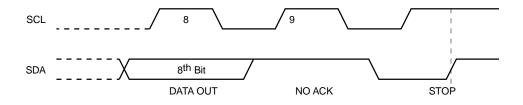


Figure 10: Selective Read Sequence

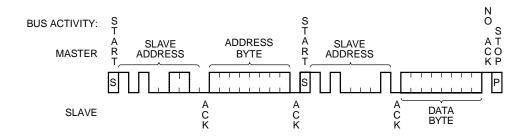
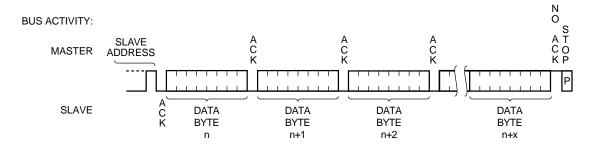
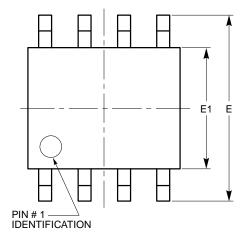


Figure 11: Sequential Read Sequence



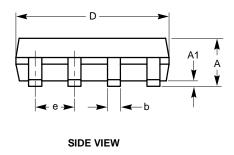
## **PACKAGE OUTLINE DRAWINGS**

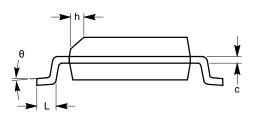
SOIC 8-Lead 150mils (W) (1)(2)



SYMBOL	MIN	NOM	MAX
Α	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
С	0.19		0.25
D	4.80		5.00
Е	5.80		6.20
E1	3.80		4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	00		8°

**TOP VIEW** 



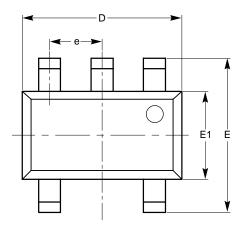


**END VIEW** 

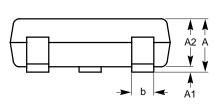
For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MS-012.

## **TSOT 5-Lead (TD)**<sup>(1)(2)</sup>

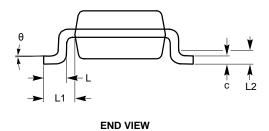


SYMBOL	MIN NOM		MAX		
Α			1.00		
A1	0.01	0.05	0.10		
A2	0.80	0.87	0.90		
b	0.30		0.45		
С	0.12	0.15	0.20		
D		2.90 BSC			
E		2.80 BSC			
E1	1.60 BSC				
е		0.95 TYP			
L	0.30	0.40	0.50		
L1		0.60 REF			
L2		0.25 BSC			
θ	00		80		
θ	00		80		





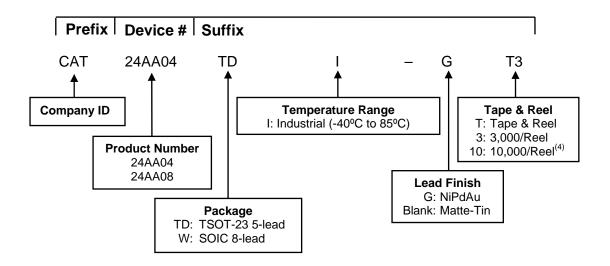
**TOP VIEW** 



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- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MO-193.

#### **EXAMPLE OF ORDERING INFORMATION**



For Product Top Mark Codes, click here: http://www.catsemi.com/techsupport/producttopmark.asp

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free).
- (2) The standard plated finish is NiPdAu.
- (3) The device used in the above example is a CAT24AA04TDI-GT3 (TSOT-23 5-lead, Industrial Temperature, NiPdAu, Tape & Reel, 3,000/Reel).
- (4) The 10,000/Reel option is only available for the TSOT-23 5-lead package.
- (5) For additional package and temperature options, please contact your nearest ON Semiconductor Sales office.

#### **REVISION HISTORY**

Date	Revision	Description	
19-Sept-08	А	Initial Issue	
23-Oct-08	В	Change logo and fine print to ON Semiconductor	

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